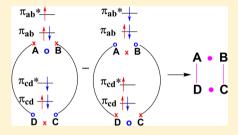


Three-Electron Bond Valence-Bond Structures for the Ditetracyanoethylene Dianion

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ABSTRACT: Using valence-bond structures of the types $\dot{A} \cdot \dot{B}$ and A : B or $A \rightarrow B$ to represent diatomic three-electron bonds, two types of valence-bond structures are constructed for the cyclic 6-electron 4-center bonding unit that is present in the ditetracyanoethylene dianion. These latter valence-bond structures, which are obtained by singlet spin-pairing the antibonding electrons of two three-electron bonds, are examples of increased-valence structures. It is shown that increasedvalence structures that use the $\dot{\mathbf{A}} \cdot \dot{\mathbf{B}}$ three-electron bond structure, which relate easily to their component Lewis structures, should be preferred to those that involve the A∴B or A-B three-electron bond structures. STO-6G weights are reported for the two 6-electron 4-center increased-valence structures for the $[C_2]_2^2$ component of the ditetracyanoethylene



■ INTRODUCTION

dianion.

In a recent paper, 1 Braida, Hiberty, and co-workers elucidated the nature of the multicenter bonding that arises in the central, rectangular C₄ component of the ditetracyanoethylene dianion complex $[TCNE]_2^{2-}$. They used ab initio valence-bond (VB) theory coupled with Quantum Monte Carlo methods. The analysis is interesting because as Schemes 2, 4, and 7 of ref 1 show, the C_4 component of $[TCNE]_2^{2-}$ involves a cyclic 6electron 4-center bonding unit, i.e. six electron distributed among four overlapping atomic orbitals (AOs), as shown in Scheme 2 of ref 1. This bonding unit helps to bind together the two [TCNE] radicals, each of which possesses a diatomic three-electron bond (or three-electron two-orbital bond), symbolized as A.: B in ref 1.

The authors of ref 1 did not realize that, since 1980, VB and related molecular orbital (MO) theories for rectangular, square, and extended 6-electron 4-center bonding units had been published on a number of occasions,² and it had been noted in ref 2e that the intermolecular C-C bonding for [TCNE]₂²⁻ (with three-electron bonds as components) can be similarly described.

Each of the ref 2 publications uses $\dot{\mathbf{A}} \cdot \dot{\mathbf{B}}$ as the VB structure for a three-electron bond, whose orbital occupations differ (see below) from those for A.: B. The 6-electron 4-center VB structures of ref 2 are examples of "increased-valence" structures, 2-5 for which more electrons participate in bonding than does occur in the Lewis structures 1-10 in Scheme 4 of ref 1, or Figure 3 below.

In this Letter, I show why the increased-valence structures of ref 2 for 6-electron 4-center bonding units should be preferred to the 6-electron 4-center bonding VB structures of Scheme 7 of ref 1, which involve the A:B type three-electron bond structures.

This preference to use $\dot{\mathbf{A}} \cdot \dot{\mathbf{B}}$ as the three-electron bond structure is all-important because increased-valence structures for electron-rich molecules, with three-electron bonds as

diatomic components, are considered to be part of the "intellectual heritage" of qualitative VB theory. Therefore, increased-valence structures should use the best type of VB symbolism to represent them.

To illustrate aspects of theory, the results of some STO-6G VB calculations are reported for the Na₂²⁺[C₂]₂²⁻ component of $Na_2^{2+}[C_2H_4]_2^{2-}$ of ref 1.

VALENCE BOND STRUCTURES FOR THE DIATOMIC THREE-ELECTRON BOND

For the central, rectangular C_4 component of $[TCNE]_2^{\ 2^-}$, in Scheme 7 of ref 1 there are four (homopolar) three-electron

bonds of the type $(\pi)^2(\pi^*)^1 = \mathbf{C} \ \mathbf{C} \ \leftrightarrow \ \mathbf{C} \ \mathbf{C}$, as in Scheme 3 of ref 1, in which π and π^* are bonding and antibonding MOs. Generalizing (for simplicity, without atomic formal charges), we have $(\pi_{ab})^2(\pi_{ab}^*)^1 = \dot{A} \ddot{B} \leftrightarrow \ddot{A} \dot{B} = (a)^1(b)^2 + (a)^2(b)^1$, in which a and b are overlapping $2p\pi$ atomic orbitals (AOs), and $\pi_{ab} = a + b$ and $\pi_{ab}^* = a - b$ are the resulting bonding and antibonding MOs.

In Scheme 7 of ref 1, the A.: B type of VB structure is used to symbolize each $(\pi_{ab})^2(\pi_{ab}^*)^1$ three-electron bond configuration, in which the top dot is the antibonding electron. On occasions, A.:B is also written as $A \stackrel{\cdot}{\leftarrow} B.^{2d,3-5}$ Each of A.:B or $A \stackrel{\cdot}{\leftarrow} B$ (as well as the earlier Pauling VB structure⁶ A···B, which has been used recently in refs 7 and 8) is of course equivalent to the Å $\ddot{\mathbf{B}} \leftrightarrow \ddot{\mathbf{A}} \ddot{\mathbf{B}}$ bonding resonance. In Scheme 7 of ref 1, the two antibonding electrons in the two three-electron bonds for [TCNE]₂²⁻ have opposed spins. Because their orbitals overlap, the ground-state involves singlet spin-pairing for these electrons.

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In 1960, Green and Linnett⁹ transformed the $(\pi_{ab})^2(\pi_{ab}^*)^1$ -type MO configuration to show that it is proportional to the $(a)^1(\pi_{ab})^1(b)^1$ configuration,^{2–5,9} with the spins of the a and b electrons opposed to that of the π_{ab} electron, as in Figure 1.

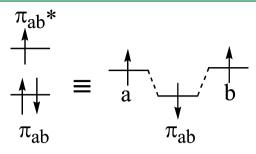


Figure 1. $(\pi_{ab})^2(\pi_{ab}^*)^1 \propto (a)^1(\pi_{ab})^1(b)^1$ (for $S = S_z = 1/2$ electron spin quantum numbers).

Using crosses and circles (\mathbf{x} and \mathbf{o}) to represent electrons with s_z spin quantum numbers of +1/2 and -1/2, the resulting Green-Linnett VB structure is $\mathbf{A} \mathbf{o} \mathbf{B}$ and $\mathbf{A} \mathbf{x} \mathbf{B}$ when the antibonding π_{ab}^* electron has $s_z = +1/2$ and -1/2, respectively. If electron spins are not indicated, the Green-Linnett VB structure is $\dot{\mathbf{A}} \cdot \dot{\mathbf{B}}$.

■ VALENCE BOND STRUCTURES FOR CYCLIC 6-ELECTRON 4-CENTER BONDING UNIT

(a). Using $\dot{\mathbf{A}} \cdot \dot{\mathbf{B}}$ Type VB Structures for Three-Electron Bonds. Using the $\dot{\mathbf{A}} \cdot \dot{\mathbf{B}}$ type VB structure for a three-electron bond, it was shown in refs 2a–2d that when the antibonding electrons of two three-electron bond structures are singlet spin-paired, as in Figure 2, the cyclic 6-electron 4-center VB

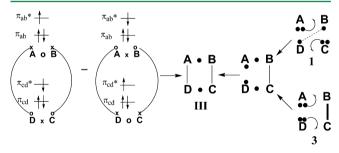


Figure 2. Construction of VB structure **III** (or **I**) by (i) singlet spin-pairing the antibonding electrons of the $(\pi_{ab})^2(\pi_{ab}^*)^1$ and $(\pi_{cd})^2(\pi_{cd}^*)^1$ three-electron bond configurations; (ii) delocalization of lone-pair electrons of the Lewis structures **1** and **3** of Scheme 4 of ref 1 (or Figure 3 here) into the π_{ab} and π_{cd} bonding MOs. The **A–B** and **C–D** bonds are in-plane π bonds (using $2p_y$ AOs), whereas the **A–D** and **B–C** bonds are σ -bonds.

structures of the types I^{2d} and II^{2d} or III^{2a-c} and IV^{2a-c} are obtained. (In III and IV, the electrons that form the electron-pair bonds in I and II are not indicated.)

These VB structures involve fractional¹⁰ (see below) nearest-neighbor and non-neighbor electron-pair bonds,^{2,3} as well as one-electron bonds. For simplicity in representation of VB structures of this type, only the nearest-neighbor (B–C, A–D,

A–B, and **C–D**) electron-pair bonds are indicated.^{2–5,10} However, if the non-neighbor **A–C** and **B–D** bonds are also included, structure **I** for example becomes structure **Ia**.

The lower-energy resonance between VB structures I and II or III and IV corresponds to the covalent component of a MO-configuration interaction wave function^{2b-d,11} constructed from the four AOs.

Using identities of the type $\dot{\bf A} \cdot \dot{\bf B} = \dot{\bf A} \, \ddot{\bf B} \leftrightarrow \ddot{\bf A} \, \dot{\bf B}$ and Heitler-London AO wave functions for electron-pair bonds (for example, a(1)b(2) + b(1)a(2) for the A–B electron-pair of VB structure II (or IV)), it is easy to deduce² that I (or III) and II (or IV) are equivalent to the $1 \leftrightarrow 2 \leftrightarrow 3 \leftrightarrow 4$ and $1 \leftrightarrow 2 \leftrightarrow 5 \leftrightarrow 6$ Lewis structure resonances, respectively, for which the Lewis VB structures 1–6 are displayed in Scheme 4 of ref 1 or Figure 3 here.

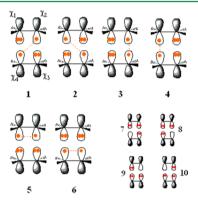


Figure 3. Lewis VB structures **1–6**. The χ_1 , χ_2 , χ_3 , and χ_4 of ref 1 correspond to the a, b, c, and d AOs of this Letter. Structures **7–10** were not included in the VB calculations of ref 1 for the unsubstituted $\mathrm{Na_2}^{2+}[\mathrm{C_2H_4}]_2^{2-}$ diethylene complex. Reprinted with permission from ref 1. Copyright 2013 American Chemical Society.

Because each of the Lewis structures 3–6 has a nearest-neighbor (B–C, A–D, A–B, or C–D) electron-pair bond, and these bonds are absent from the "long-bond" Lewis structures 1 and 2, the nearest-neighbor electron-pair bonds in VB structures I–IV are fractional^{2,3,10} when structures 1 and 2 participate in resonance with either 3 and 4 or 5 and 6.

(b). Weights for VB Structures 1–6, I or III and II or IV. In Table 2 of ref 1, the Coulson-Chirgwin weights 12 for structures 1–6 of Table 1 are reported again here in Table 1 for

Table 1. Coulson-Chirgwin Weights for Structures 1-6 of Figure 3 and I and II (or III and IV)

	1,2	3,4	5,6	I	II
ref 1, Table 2	0.219	0.211	0.071		
$[C_2]_2^{2-}$ STO-6G, 10 electrons	0.237	0.203	0.060	0.733	0.267
$[C_2]_2^{2-}$ STO-6G, 26 electrons	0.253	0.209	0.038	0.795	0.205

the unsubstituted $Na_2^{2+}[C_2H_4]_2^{2-}$ diethylene complex. Here we report the results of two sets of STO-6G VB calculations for the $Na_2^{2+}[C_2]_2^{2-}$ component of $Na_2^{2+}[C_2H_4]_2^{2-}$ (see the Appendix for methodology) in order to focus attention on the cyclic 6-electron 4-center bonding unit:

(a) including only the electrons that form the $[C_2]_2^{2-}$ 6-electron 4-center bonding unit, together with four electrons that form the two C–C σ -bonds of the diethylene; (b)

including the remaining 16 electrons of $\left[C_2\right]_2^{2-}$ in 1s and 2s AOs.

The STO-6G weights for structures 1-6 (Table 1) are similar to those reported in ref 1, which implies that increased-valence structure I ($\equiv 1 \leftrightarrow 2 \leftrightarrow 3 \leftrightarrow 4$) should have a substantially larger weight than has increased-valence structure II ($\equiv 1 \leftrightarrow 2 \leftrightarrow 5 \leftrightarrow 6$). The results of the STO-6G calculations (Table 1) show that structure I is dominant.

Two reasons account for the larger weights for structures 3, 4, and I compared with those for structures 5, 6, and II.

(i) To first order in AO overlap

$$\langle \Psi_1 | \Psi_3 \rangle = \langle \Psi_1 | \Psi_4 \rangle = \langle \Psi_2 | \Psi_3 \rangle = \langle \Psi_2 | \Psi_4 \rangle \propto S_{ab} = S_{cd}$$

= 0.43¹

$$\langle \Psi_1 | \Psi_5 \rangle = \langle \Psi_1 | \Psi_6 \rangle = \langle \Psi_2 | \Psi_5 \rangle = \langle \Psi_2 | \Psi_6 \rangle \propto S_{ad} = S_{bc}$$

= 0.19¹

i.e. the Ψ_1 and Ψ_2 wave functions for structures 1 and 2 overlap better with Ψ_3 and Ψ_4 than they do with Ψ_5 and Ψ_6 .

(ii) Like atomic formal charges are better separated for structures 3 and 4 than they are for structures 5 and 6.

Because there are three nonequivalent types of VB structures in Figure 3, the 1 \leftrightarrow 2 \leftrightarrow 3 \leftrightarrow 4 \leftrightarrow 5 \leftrightarrow 6 resonance involves two independent variational parameters. The $\Psi = \Psi_I + \lambda \Psi_{II}$ involves only one variational parameter (λ). Therefore, the energy for the I \leftrightarrow II resonance must lie above the energy for the 1 \leftrightarrow 2 \leftrightarrow 3 \leftrightarrow 4 \leftrightarrow 5 \leftrightarrow 6 resonance.

(c). Using A.:B Type VB Structures for Three-Electron Bonds. Scheme 7 of ref 1 uses A.:B as the three-electron bond type of VB structure. When the antibonding electrons for each pair of A.:B (or A - B)^{2d,3-5} three-electron bonds are singlet spin-paired, VB structures V and VI or VII and VIII are obtained.

Because the wave functions for $\dot{A} \cdot \dot{B}$ and $A \cdot B$ (or A - B) are equivalent (cf. Figure 1), the VB structures of V - VIII can also be considered to be examples of "increased-valence" structures. However, structures V - VIII show less clearly the nature of the bonding between pairs of atoms than do VB structures I - IV.

The use of the identity $\dot{\mathbf{A}} \cdot \dot{\mathbf{B}} = \dot{\mathbf{A}} \ \ddot{\mathbf{B}} \leftrightarrow \ddot{\mathbf{A}} \ \dot{\mathbf{B}}$ relates the increased-valence structures I–IV more immediately to their component Lewis VB structures 1–6 than do either $\mathbf{A} \cdot \mathbf{B}$ or $\mathbf{A} + \mathbf{B} = \dot{\mathbf{A}} \ \ddot{\mathbf{B}} \leftrightarrow \ddot{\mathbf{A}} \ \dot{\mathbf{B}}$ for increased-valence structures V–VIII. The location of the electron-pair bond that links the two three-electron bonds in each of the structures V–VIII does not occur in any of its component Lewis structures.

CONCLUSION

Three-electron bond structures of the $\dot{\bf A} \cdot \dot{\bf B}$ type occur extensively as components of easily constructed increased-valence structures. These types of increased-valence structures help to provide qualitative VB representations of the electronic structures for a large number of triatomic and polyatomic electron-rich molecules. In ref 13, these types of increased-valence structures are displayed for the cyclic and extended 6-electron 4-center bonding units that arise in spiral chain O₄ polymers. Some of the earlier publications that also

use increased-valence structures of types I and II (or III and IV) include those of refs 14 and 15.

APPENDIX

Method for STO 6G VB Calculations

The Na⁺-[C₂]₂²-Na⁺ geometry of ref 1 for Na⁺-[C₂H₄]₂²-Na⁺(C_A-C_B = C_C-C_D = 1.46 Å, C_A-C_D = C_B-C_C = 2.75 Å, Na⁺-Na⁺ = 6.93 Å) was used in the STO 6G VB calculations, for which the AOs a, b, c, and d are 2p_y AOs. The Na⁺ ions were replaced by H⁺ ions. The four electrons that form the C_A-C_B and C_C-C_D electron-pair σ bonds were accommodated in two σ 2p_x bonding MOs, with no 2s-2p_x hybridization. Each of the 2s and 2p AOs was assigned a C^{-1/2} Slater orbital exponent of 1.5375, and a Slater orbital exponent of 5.7 was used for the 1s AOs.

For the cyclic 6-electron 4-center bonding unit of $[C_2]_2^{2-}$, the (unnormalized) $\Psi(I) \equiv \Psi(III)$ and $\Psi(II) \equiv \Psi(IV)$ are given by eqs 1–6 (see for example eqs 1–6 of ref 14d, with k = l = 1 in the MOs)

$$\Psi(\mathbf{I}) = |\psi_{ab}\overline{\psi}_{ab}\psi_{cd}\overline{\psi}_{cd}\psi^*_{ab}\overline{\psi}^*_{cd}| + |\psi_{ab}\overline{\psi}_{ab}\psi_{cd}\overline{\psi}_{cd}\psi^*_{cd}\overline{\psi}^*_{ab}|$$

$$(1)$$

$$\propto |a \, \overline{\psi}_{ab} \psi_{cd} \, \overline{c} \, b \, \overline{d}| + |\psi_{ab} \, \overline{a} \, c \, \overline{\psi}_{cd} \, d \, \overline{b}| \tag{2}$$

$$\propto \Psi_1 + \Psi_2 - \Psi_3 - \Psi_4 \tag{3}$$

$$\Psi(\mathbf{II}) = |\psi_{ad}\overline{\psi}_{ad}\psi_{bc}\overline{\psi}_{bc}\psi^*_{ad}\overline{\psi}^*_{bc}| + |\psi_{ad}\overline{\psi}_{ad}\psi_{bc}\overline{\psi}_{bc}\psi^*_{bc}\overline{\psi}^*_{ad}|$$

$$(4)$$

$$\propto |a \, \overline{\psi}_{ad} \psi_{bc} \, \overline{c} \, d \, \overline{b}| + |\psi_{ad} \, \overline{a} \, c \, \overline{\psi}_{bc} \, b \, \overline{d}|) \tag{5}$$

$$\propto \Psi_1 + \Psi_2 - \Psi_5 - \Psi_6 \tag{6}$$

in which $\psi_{ab} = a + b$, $\psi_{cd} = c + d$, $\psi_{ad} = a + d$, and $\psi_{bc} = b + c$. The presence or absence of a bar ($\bar{}$) over the orbital specifies a β or α electron spin wavefunction.

The calculations were performed using Roso's *ab initio* VB program as used in refs 2c and 16, for example.

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Notes

The authors declare no competing financial interest.

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- (10) A fractional electron-pair bond has a bond number less than unity^{2–5} and is represented by a thin bond line in the VB structures.^{2–5} With two homopolar one-electron bonds in each of the VB structures I–IV, the fractional A–C, A–D, B–C, and B–D bond numbers are 0.25 in structures I and III. In structures II and IV, the bond number for each of the fractional A–B, A–C, B–D, and C–D bonds is also equal to 0.25 (cf. refs 2a,2b).
- (11) The three lowest-energy ${}^{1}A_{g}$ MO configurations are $\Phi_{1}=(a_{g})^{2}(b_{3u})^{2}(b_{2u})^{2}$, $\Phi_{2}=(a_{g})^{2}(b_{3u})^{2}(b_{1g})^{2}$, and $\Phi_{3}=(a_{g})^{2}(b_{2u})^{2}(b_{1g})^{2}$, each of which has been expressed as a $\Psi(\text{covalent})+\Psi(\text{ionic})$ type wave function. There are two $\Psi(\text{covalent})$ type wave functions, which relate to structures 1 and 2 and either 3 and 4 or 5 and 6 of Figure 3. For the $\Psi(\text{ionic})$ type wave functions, structures 7–10 of Scheme 4 of ref 1 replace structures 1 and 2. The a_{g} , b_{3u} , b_{2u} , and b_{1g} MOs are those of Scheme 2 of ref 1. Other theorems, which are not needed here, can also be developed.
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■ NOTE ADDED IN PROOF

See ref 2d and ref 36 therein for diatomic three-electron bond theory with three or more AOs. It has also been concluded that the three-electron bond "probes the ultimate limits of valence for electron-rich molecules."¹⁷